TOSHIBA

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

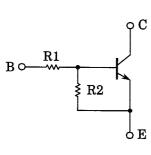
RN1961,RN1962,RN1963 RN1964,RN1965,RN1966

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

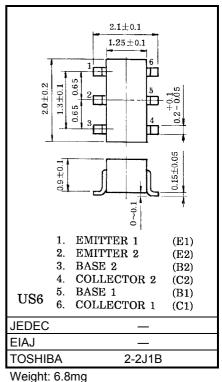
- Including two devices in US6 (ultra super mini type 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2961~RN2966

Equivalent Circuit and Bias Resistor Values

Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

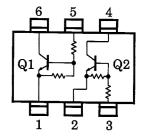


Type No.	R1 (kΩ)	R2 (kΩ)			
RN1961	4.7	4.7			
RN1962	10	10			
RN1963	22	22			
RN1964	47	47			
RN1965	2.2	47			
RN1966	4.7	47			



Equivalent Circuit (Top View)

Characteristic Symbol Rating Unit Collector-base voltage 50 ٧ **V**CBO RN1961~1966 Collector-emitter voltage 50 V VCEO RN1961~1964 10 Emitter-base voltage VEBO V RN1965, 1966 5 Collector current 100 Ic mΑ Collector power dissipation P_{C}^{*} 200 mW RN1961~1966 Junction temperature °C Тj 150 Storage temperature range -55~150 °C Tstg



*: Total rating

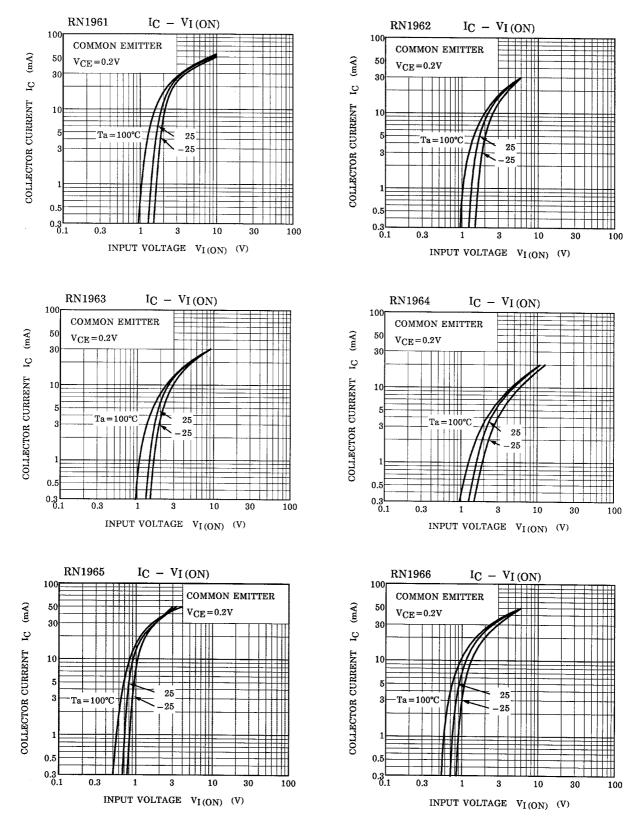
Unit: mm

Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteris	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current	RN1961~1966	I _{CBO}	-	V _{CB} = 50V, I _E = 0	—	_	100	nA
Collector cut-on current		I _{CEO}	_	V _{CE} = 50V, I _B = 0	_	_	500	
	RN1961	IEBO	_	- V _{EB} = 10V, I _C = 0	0.82	_	1.52	- mA
	RN1962		_		0.38	_	0.71	
Funither out off ourset	RN1963		_		0.17	-	0.33	
Emitter cut-off current	RN1964		_		0.082	_	0.15	
	RN1965		_	V _{EB} = 5V, I _C = 0	0.078	_	0.145	
	RN1966		_		0.074	_	0.138	
	RN1961	h _{FE}	—	V _{CE} = 5V, I _C = 10mA	30	_	—	· ·
	RN1962		_		50	_	—	
	RN1963		_		70	_	_	
DC current gain	RN1964		_		80	_	_	
	RN1965		_		80	_	_	
	RN1966		_		80	_	_	
Collector-emitter saturation voltage	RN1961~1966	V _{CE (sat)}	-	I _C = 5mA, I _B = 0.25mA	_	0.1	0.3	V
	RN1961	Vi (on)	-	- V _{CE} = 0.2V, I _C = 5mA	1.1	_	2.0	V
	RN1962		_		1.2	_	2.4	
	RN1963		_		1.3	_	3.0	
Input voltage (ON)	RN1964		_		1.5	_	5.0	
	RN1965		_		0.6	_	1.1	
	RN1966		_		0.7	_	1.3	
	RN1961~1964	V _{I (OFF)}	—	V _{CE} = 5V, I _C = 0.1mA	1.0	_	1.5	v
Input voltage (OFF)	RN1965, 1966		_		0.5	_	0.8	
Translation frequency	RN1961~1966	f _T	—	V _{CE} = 10V, I _C = 5mA	_	250	—	MHz
Collector output capacitance	RN1961~1966	C _{ob}	-	V _{CB} = 10V, I _E = 0, f = 1MHz	-	3	6	pF
	RN1961	R1	_	-	3.29	4.7	6.11	- - kΩ
	RN1962		_		7	10	13	
	RN1963		_		15.4	22	28.6	
Input resistor	RN1964		_		32.9	47	61.1	
	RN1965		_		1.54	2.2	2.86	
	RN1966		_	1	3.29	4.7	6.11	
	RN1961~1965	R1/R2	-		0.9	1.0	1.1	
Resistor ratio	RN1965		_		0.0421	0.0468	0.0515	
	RN1966		_		0.09	0.1	0.11	

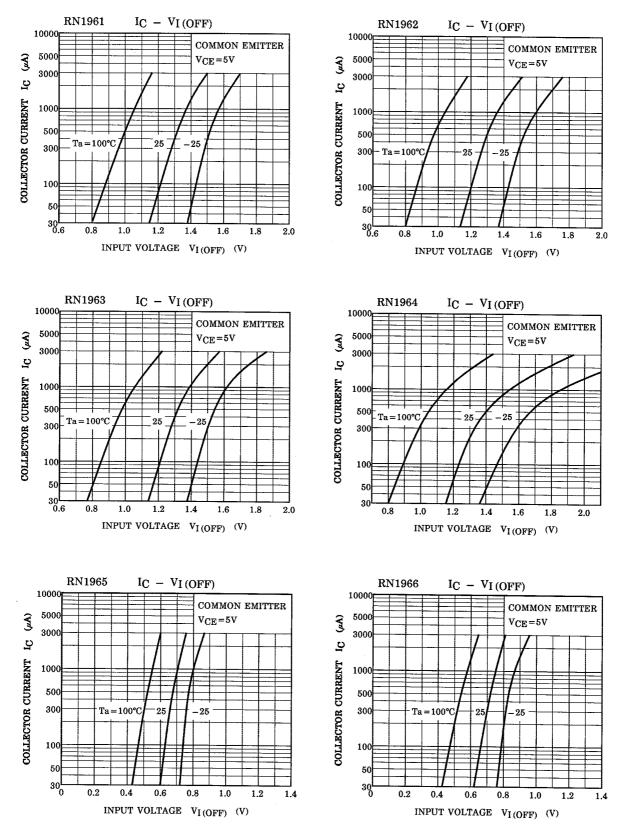
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(Q1, Q2 Common)

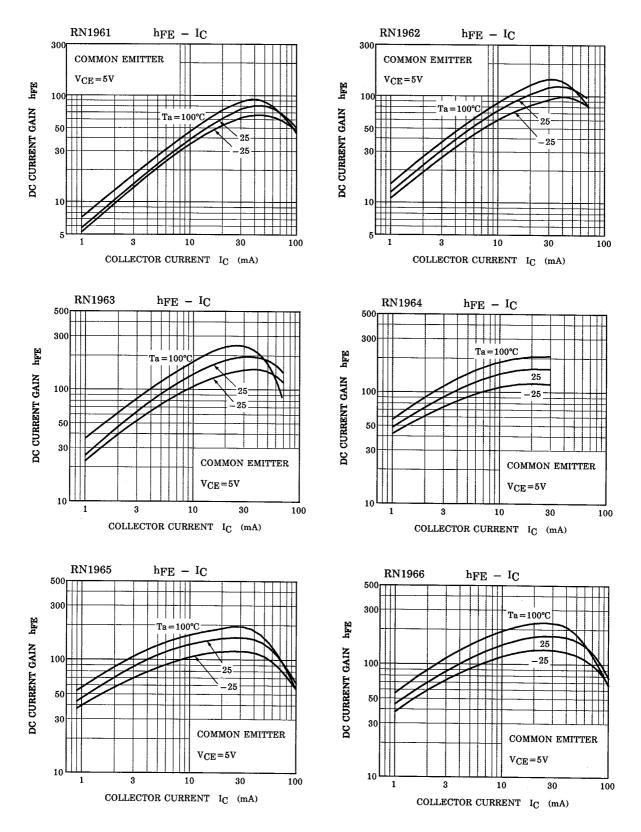


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(Q1, Q2 Common)



(Q1, Q2 Common)



Type Name	Marking		
RN1961	Type Name XXA UUU		
RN1962	Type Name X X B HEE		
RN1963	Type Name XXC UUU		
RN1964	Type Name XXD HEE		
RN1965	Type Name XXE BBB		
RN1966	Type Name XXF UTT		

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